# NSN 5961-01-051-6656

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## Inclosure Material:

Ceramic

## **Overall Length:**

Between 0.890 inches and 0.910 inches

## **Overall Height:**

0.240 inches

## **Overall Width:**

Between 0.376 inches and 0.410 inches

#### **End Application:**

An/fps115

#### Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Emitter

### **Mounting Method:**

Unthreaded hole

### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

65.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, instantaneous

#### **Current Rating Per Characteristic:**

2.50 amperes source cutoff current

#### **Power Rating Per Characteristic:**

20.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

T.O. 31p6-2fps115-62; n/h/a radar transmitter; junction pattern arrangement: npn

### Terminal Type And Quantity:

2 ribbon or 1 tab, solder lug

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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